



OPA354 OPA2354 OPA4354

SBOS233D - MARCH 2002- REVISED FEBRUARY 2005

勝 特 力 材 料 886-3-5753170 胜特力电子(上海) 86-21-34970699 胜特力电子(深圳) 86-755-83298787 Http://www.100y.com.tw

250MHz, Rail-to-Rail I/O, CMOS OPERATIONAL AMPLIFIERS

FEATURES

UNITY-GAIN BANDWIDTH: 250MHz
WIDE BANDWIDTH: 100MHz GBW

HIGH SLEW RATE: 150V/μs

● LOW NOISE: 6.5nV/√Hz

RAIL-TO-RAIL I/O

HIGH OUTPUT CURRENT: > 100mA

 EXCELLENT VIDEO PERFORMANCE: Diff Gain: 0.02%, Diff Phase: 0.09°
0.1dB Gain Flatness: 40MHz

LOW INPUT BIAS CURRENT: 3pA

QUIESCENT CURRENT: 4.9mA

THERMAL SHUTDOWN

SUPPLY RANGE: 2.5V to 5.5V

MicroSIZE AND PowerPAD™ PACKAGES

APPLICATIONS

- VIDEO PROCESSING
- ULTRASOUND
- OPTICAL NETWORKING, TUNABLE LASERS
- PHOTODIODE TRANSIMPEDANCE AMPS
- ACTIVE FILTERS
- HIGH-SPEED INTEGRATORS
- ANALOG-TO-DIGITAL (A/D) CONVERTER INPUT BUFFERS
- DIGITAL-TO-ANALOG (D/A) CONVERTER OUTPUT AMPLIFIERS
- BARCODE SCANNERS
- COMMUNICATIONS

PowerPAD is a trademark of Texas Instruments

DESCRIPTION

The OPA354 series of high-speed, voltage-feedback CMOS operational amplifiers are designed for video and other applications requiring wide bandwidth. They are unity-gain stable and can drive large output currents. Differential gain is 0.02% and differential phase is 0.09°. Quiescent current is only 4.9mA per channel.

The OPA354 series op amps are optimized for operation on single or dual supplies as low as 2.5V (± 1.25 V) and up to 5.5V (± 2.75 V). Common-mode input range extends beyond the supplies. The output swing is within 100mV of the rails, supporting wide dynamic range.

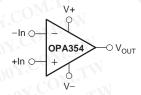
For applications requiring the full 100mA continuous output current, single and dual SO-8 PowerPAD versions are available.

The single version (OPA354), is available in the tiny SOT23-5 and SO-8 PowerPAD packages. The dual version (OPA2354) comes in the miniature MSOP-8 and SO-8 PowerPAD packages. The quad version (OPA4354) is offered in TSSOP-14 and SO-14 packages.

Multichannel versions feature completely independent circuitry for lowest crosstalk and freedom from interaction. All are specified over the extended -40°C to +125°C temperature range.

OPAx354 RELATED PRODUCTS

FEATURES	PRODUCT
Shutdown Version of OPA354 Family	OPAx357
200MHz GBW, Rail-to-Rail Output, CMOS, Shutdown	OPAx355
200MHz GBW, Rail-to-Rail Output, CMOS	OPAx356
38MHz GBW, Rail-to-Rail Input/Output, CMOS	OPAx350/3
75MHz BW G = 2, Rail-to-Rail Output	OPAx631
150MHz BW G = 2, Rail-to-Rail Output	OPAx634
100MHz BW, Differential Input/Output, 3.3V Supply	THS412x





Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

All trademarks are the property of their respective owners.





ABSOLUTE MAXIMUM RATINGS(1)

Supply Voltage, V+ to \	/	7.5V
Signal Input Terminals	Voltage(2)	. $(V-) - (0.5V)$ to $(V+) + (0.5V)$
COM.	Current(2)	10mA
Output Short-Circuit(3)		Continuous
Operating Temperature		55°C to +150°C
Storage Temperature		65°C to +150°C
Junction Temperature.		+150°C
Lead Temperature (sold	lering, 10s)	+300°C

- (1) Stresses above these ratings may cause permanent damage. Exposure to absolute maximum conditions for extended periods may degrade device reliability. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those specified is not supported.
- (2) Input terminals are diode-clamped to the power-supply rails. Input signals that can swing more than 0.5V beyond the supply rails should be current limited to 10mA or less.
- (3) Short-circuit to ground, one amplifier per package.



ELECTROSTATIC DISCHARGE SENSITIVITY

This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

PACKAGE/ORDERING INFORMATION(1)

PRODUCT	PACKAGE-LEAD	PACKAGE DESIGNATOR	SPECIFIED TEMPERATURE RANGE	PACKAGE MARKING	ORDERING NUMBER	TRANSPORT MEDIA, QUANTITY
OPA354	SO-8 PowerPAD	DDA "	-40°C to +125°C	OPA354A	OPA354AIDDA OPA354AIDDAR	Rails, 97 Tape and Reel, 2500
OPA354	SOT23-5	DBV "	-40°C to +125°C	OABI "	OPA354AIDBVT OPA354AIDBVR	Tape and Reel, 250 Tape and Reel, 3000
OPA2354	SO-8 PowerPAD	DDA "	-40°C to +125°C	OPA2354A "	OPA2354AIDDA OPA2354AIDDAR	Rails, 97 Tape and Reel, 2500
OPA2354	MSOP-8	DGK "	-40°C to +125°C	OACI "	OPA2354AIDGKT OPA2354AIDGKR	Tape and Reel, 250 Tape and Reel, 2500
OPA4354 "	SO-14	D,	-40°C to +125°C	OPA4354A "	OPA4354AID OPA4354AIDR	Rails, 58 Tape and Reel, 2500
OPA4354	TSSOP-14	PW "	-40°C to +125°C	OPA4354A "	OPA4354AIPWT OPA4354AIPWR	Tape and Reel, 250 Tape and Reel, 2500

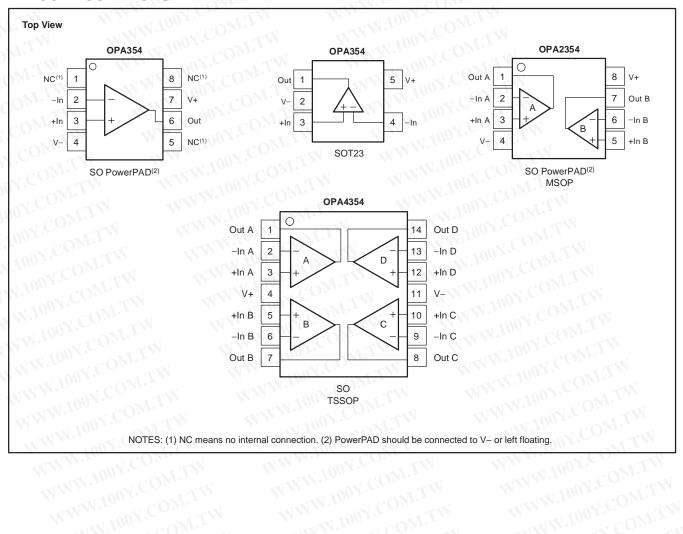
⁽¹⁾ For the most current package and ordering information, see the Package Option Addendum located at the end of this data sheet.

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PIN CONFIGURATIONS



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WWW.100

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ELECTRICAL CHARACTERISTICS: V_S = +2.7V to +5.5V Single-Supply

Boldface limits apply over the specified temperature range, $T_A = -40^{\circ}C$ to $+125^{\circ}C$.

At $T_A = +25^{\circ}C$, $R_F = 0\Omega$, $R_I = 1k\Omega$, and connected to $V_S/2$, unless otherwise noted.

COM. TW WWW.100			OPA2			
PARAMETER	VW.100	CONDITIONS	MIN	TYP	MAX	UNITS
FFSET VOLTAGE	- N 10	. COM: I W. 101	CON	1.1		
nput Offset Voltage	Vos	$V_S = +5V$	OX.C	±2	±8	mV
	-XIW.1	Specified Temperature Range	47 CO	Mr.	±10	mV
vs Temperature	dV _{os} /dT	Specified Temperature Range	001.	±4		μ V/ °C
s Power Supply	PSRR	$V_S = +2.7V$ to +5.5V, $V_{CM} = (V_S/2) - 0.15V$	ov.C	±200	√ ±800	μV/V
OY.COM.TW	M.	Specified Temperature Range	100 7.	OM.I	±900	μ V/V
PUT BIAS CURRENT	MW	TIOOY.CO TITH	100 X.		M	
out Bias Current	I _B		N. P	3	±50	pА
out Offset Current	I _{os}	M.1001.	W.100 .	±1	±50	pA
DISE	W		100		LTW	
out Voltage Noise Density	e _n	f = 1MHz	NN.	6.5	W	nV/√Hz
rrent Noise Density	in	f = 1MHz	-TW.10	50	M.I.	fA/√Hz
UT VOLTAGE RANGE	V	W. 100X.CO.LTW	-x1 1	001	MIM	
ommon-Mode Voltage Range	V_{CM}		(V-) - 0.1	anv.C	(V+) + 0.1	V
ommon-Mode Rejection Ratio	CMRR	$V_S = +5.5V, -0.1V < V_{CM} < +3.5V$	66	80	'OM.	dB
	V	Specified Temperature Range	64	any!	T. T.	dB
		$V_S = +5.5V, -0.1V < V_{CM} < +5.6V$	56	68	COM	dB
WW. CO. C.	W	Specified Temperature Range	55	1 100 X		dB
PUT IMPEDANCE			WW	W	V.Com	TW
ferential	1.		- 1	1013 2	- COM	Ω pF
mmon-Mode	TW	WWW.100Y.Co.TY	MA	1013 2	01.00	Ω pF
EN-LOOP GAIN	AOL	$V_S = +5V$, $+0.3V < V_O < +4.7V$	94	110	VI CO	dB
pecified Temperature Range	$M_{1,T}$	$V_S = +5V, +0.4V < V_O < +4.6V$	90	WW.	T CC	dB
QUENCY RESPONSE	TIN	WW. 1007. OM.TW		- TAN	1001.	M_{II}
all-Signal Bandwidth	t_ _{3dB}	$G = +1, V_0 = 100 \text{mV}_{PP}, R_F = 25 \Omega$		250	AND Y.C	MHz
	f_3dB	$G = +2, V_O = 100 \text{mV}_{PP}$	- T	90	1.100	MHz
n-Bandwidth Product	GBW	G = +10	N	100	-11007.	MHz
dwidth for 0.1dB Gain Flatness	f _{0.1dB}	$G = +2, V_O = 100 \text{mV}_{PP}$	- 1	40	N. I	MHz
w Rate	SR	$V_S = +5V, G = +1, 4V \text{ Step}$	111	150	2X 100 X	V/μs
	COM.	$V_S = +5V, G = +1, 2V \text{ Step}$	TV	130	111.	V/µs
	Ma	V _S = +3V, G = +1, 2V Step	11.	110	W.100	V/μs
e-and-Fall Time	A'CON,	$G = +1$, $V_0 = 200 \text{mV}_{PP}$, 10% to 90%	WT	2	11 1.	ns
	401	$G = +1$, $V_0 = 2V_{PB}$ 10% to 90%	1.1	11	TANN. LU	ns
tling Time, 0.1%	MY.Co.	$V_S = +5V$, G = +1, 2V Output Step	WILL	30	N 1	ns
0.01%	-1 CO		MI	60	WW.	ns
erload Recovery Time	100 X.	V _{IN} • Gain = V _S	MIT	5	NY .	ns
rmonic Distortion	N.C		U. T.		MAN	L OON
nd-Harmonic	1001.	$G = +1$, $f = 1MHz$, $V_O = 2V_{PB}$, $R_L = 200\Omega$, $V_{CM} = 1.5V$	OM.	-75	TXXIV	dBc
rd-Harmonic	. Van	$G = +1$, $f = 1MHz$, $V_0 = 2V_{PB}$, $R_L = 200\Omega$, $V_{CM} = 1.5V$	ATT	-83	M. M.	dBc
erential Gain Error	N.100	NTSC, $R_L = 150\Omega$	CO_{Mr}	0.02	-XIVN	%
erential Phase Error	1007	NTSC, $R_L = 150\Omega$	TAN.	0.09	111.	degrees
annel-to-Channel Crosstalk	M.10		A COA.	TIN		114.
armor to originator orocotant	00	f = 5MHz	" and	-100	41	dB
DPA2354			1 - (1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1	-84	-1	

⁽¹⁾ See typical characteristics Output Voltage Swing vs Output Current.

⁽²⁾ Specified by design.



ELECTRICAL CHARACTERISTICS: $V_S = +2.7V$ to +5.5V Single-Supply (continued)

Boldface limits apply over the specified temperature range, $T_A = -40^{\circ}C$ to $+125^{\circ}C$.

At $T_A = +25^{\circ}$ C, $R_F = 0\Omega$, $R_I = 1k\Omega$, and connected to $V_S/2$, unless otherwise noted.

N.T. WWW.IOO.		M. TW WWW.tony.CC	OPA			
PARAMETER	~ √ C	CONDITIONS	MIN	TYP	MAX	UNITS
OUTPUT	00 1.	CONT. IV. TOW.	OM	- 1		
oltage Output Swing from Rail	MANY.	$V_S = +5V, R_L = 1k\Omega, A_{OL} > 94dB$		0.1	0.3	V
Specified Temperature Range	To	$V_{s} = +5V$, $R_{L} = 1k\Omega$, $A_{OL} > 90dB$		TV	0.4	V
Output Current(1)(2), Single, Dual, Quad	10 lo	$V_S = +5V$	100	7		mA
	N	V _S = +3V		50		mA
Closed-Loop Output Impedance	W.104	f < 100kHz		0.05		Ω
Open-Loop Output Resistance	Ro	OY.CONITY WY		35		Ω
POWER SUPPLY	MM	COM THE WAY	any.Ct	TIN		
Specified Voltage Range	Vs	00 - COW:1.	2.7	$0_{M^{**}}$	5.5	V
Operating Voltage Range	11 4.	TONY.CO TYN WWY		2.5 to 5.5		V
Quiescent Current (per amplifier)	la	$V_s = +5V$, Enabled, $I_0 = 0$		4.9	6	mA
	M. A.	Specified Temperature Range		aoM.	7.5	mA
THERMAL SHUTDOWN	WW	WW.	1003		TW	
Junction Temperature		M.Inc. COM.		A COMP		
Shutdown	1/1/1/	100Y.		+160		°C
Reset from Shutdown	***	NW. TO V.COM		+140		°C
TEMPERATURE RANGE	7	M.Ing COM.	M.I.	√ <7 CO	NI.	
Specified Range	V	W 100Y.CO TITY	-40	00 J.	+125	°C
Operating Range		AMAN'IA COMP.	-55	ON C	+150	°C
Storage Range		M. 100 1. COM: I.	-65	100	+150	°C
Thermal Resistance	$ heta_{\sf JA}$	WWW. COX.CO		1007.		
SOT23-5, MSOP-8		WW.Inc. COM.		150		°C/W
TSSOP-14		WW. 1007.		100		°C/W
SO-14	KĪ.	MAN. TO COM		100		°C/W
SO-8 PowerPAD		M. 100 r. W. J.		65		°C/W

⁽¹⁾ See typical characteristics Output Voltage Swing vs Output Current. WWW.100Y.COM.TW

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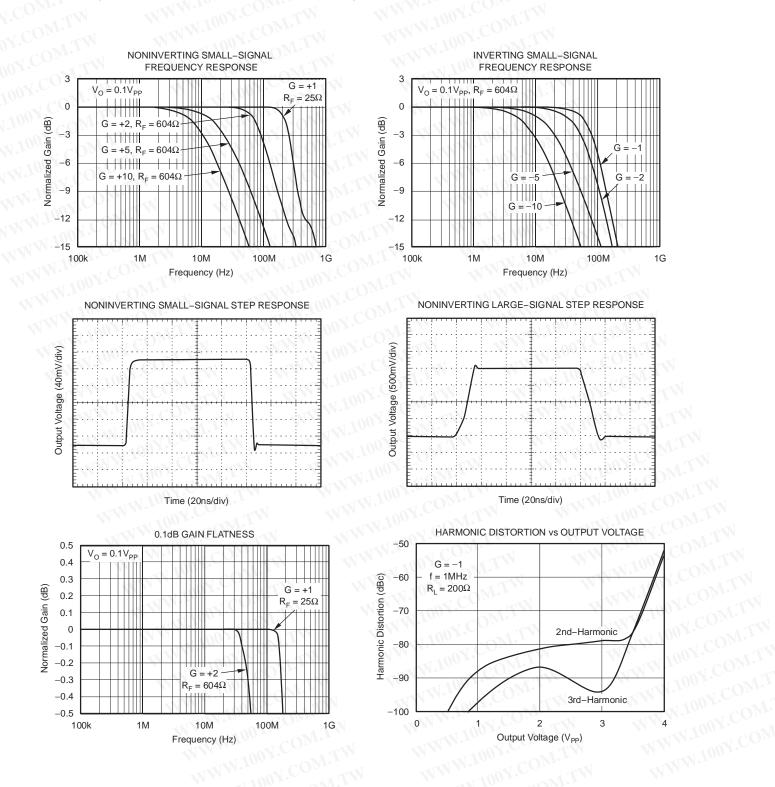
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TYPICAL CHARACTERISTICS

At $T_A = +25$ °C, $V_S = 5$ V, G = +1, $R_F = 0$ Ω, $R_L = 1$ kΩ, and connected to $V_S/2$, unless otherwise noted.

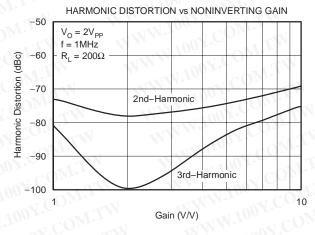


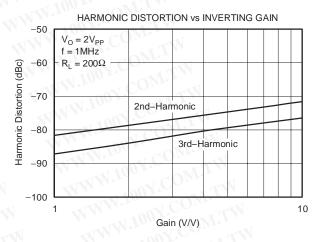
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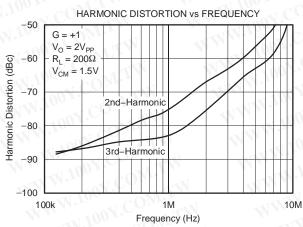
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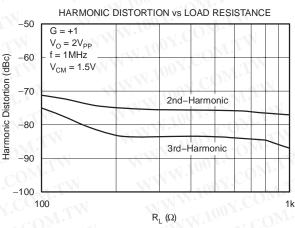


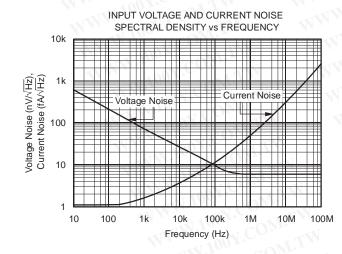
At $T_A = +25$ °C, $V_S = 5V$, G = +1, $R_F = 0\Omega$, $R_L = 1k\Omega$, and connected to $V_S/2$, unless otherwise noted.

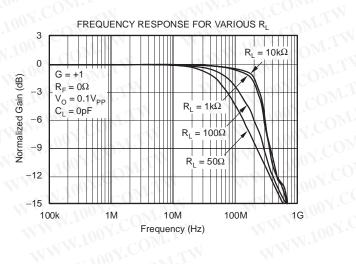






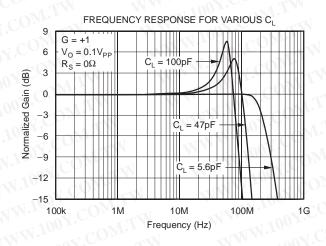


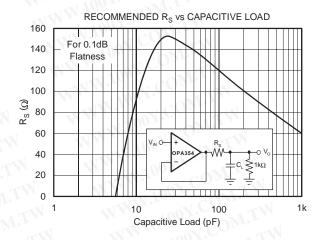


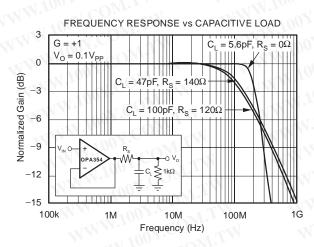


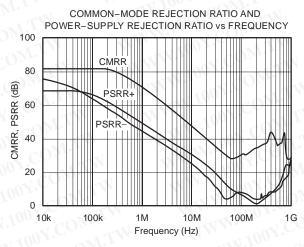


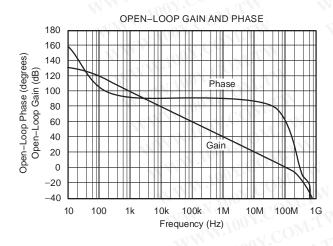
At $T_A = +25^{\circ}C$, $V_S = 5V$, G = +1, $R_F = 0\Omega$, $R_L = 1k\Omega$, and connected to $V_S/2$, unless otherwise noted.

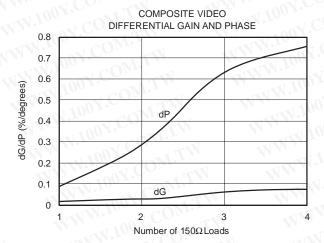






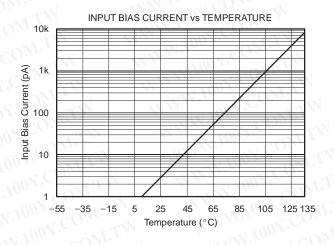


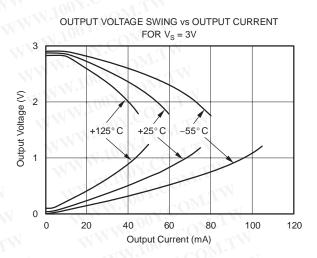


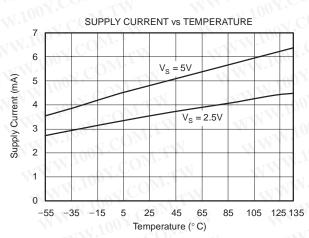


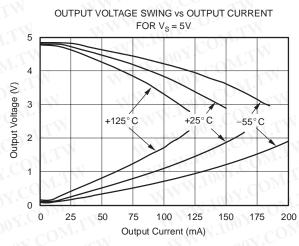


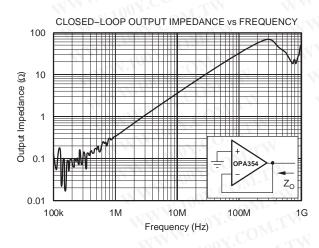
At $T_A = +25$ °C, $V_S = 5V$, G = +1, $R_F = 0\Omega$, $R_L = 1k\Omega$, and connected to $V_S/2$, unless otherwise noted.

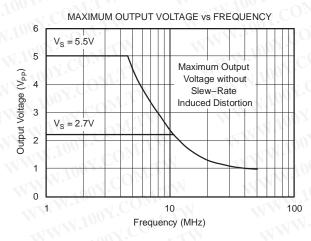






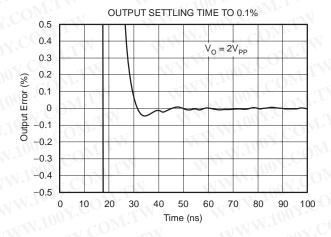


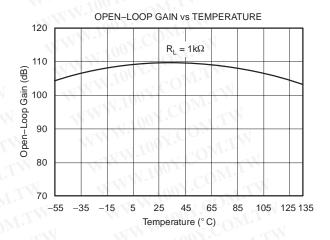


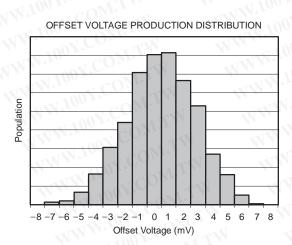


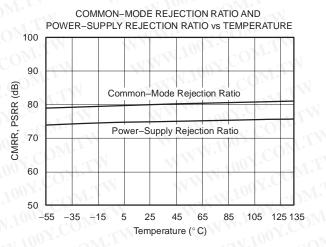


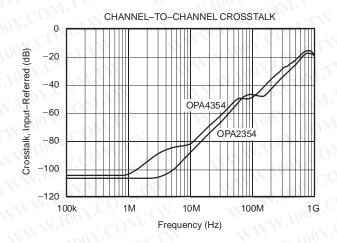
At $T_A = +25$ °C, $V_S = 5V$, G = +1, $R_F = 0\Omega$, $R_L = 1k\Omega$, and connected to $V_S/2$, unless otherwise noted.













APPLICATIONS INFORMATION

The OPA354 is a CMOS, rail-to-rail I/O, high-speed, voltage-feedback operational amplifier designed for video, high-speed, and other applications. It is available as a single, dual, or quad op amp.

The amplifier features a 100MHz gain bandwidth, and $150V/\mu s$ slew rate, but it is unity-gain stable and can be operated as a +1V/V voltage follower.

OPERATING VOLTAGE

The OPA354 is specified over a power-supply range of $\pm 2.7 \text{V}$ to $\pm 5.5 \text{V}$ ($\pm 1.35 \text{V}$ to $\pm 2.75 \text{V}$). However, the supply voltage may range from $\pm 2.5 \text{V}$ to $\pm 5.5 \text{V}$ ($\pm 1.25 \text{V}$ to $\pm 2.75 \text{V}$). Supply voltages higher than 7.5V (absolute maximum) can permanently damage the amplifier.

Parameters that vary over supply voltage or temperature are shown in the typical characteristics section of this data sheet.

RAIL-TO-RAIL INPUT

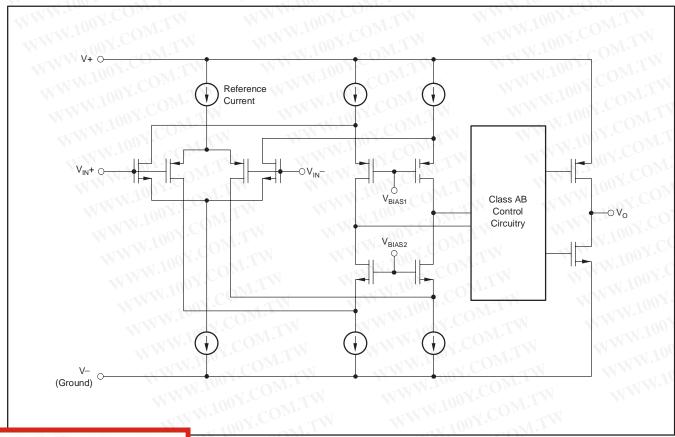
The specified input common-mode voltage range of the OPA354 extends 100mV beyond the supply rails. This is achieved with a complementary input stage—an

N-channel input differential pair in parallel with a P-channel differential pair, as shown in Figure 1. The N-channel pair is active for input voltages close to the positive rail, typically (V+)-1.2V to 100mV above the positive supply, while the P-channel pair is on for inputs from 100mV below the negative supply to approximately (V+)-1.2V. There is a small transition region, typically (V+)-1.5V to (V+)-0.9V, in which both pairs are on. This 600mV transition region can vary $\pm 500mV$ with process variation. Thus, the transition region (both input stages on) can range from (V+)-2.0V to (V+)-1.5V on the low end, up to (V+)-0.9V to (V+)-0.4V on the high end.

A double-folded cascode adds the signal from the two input pairs and presents a differential signal to the class AB output stage.

RAIL-TO-RAIL OUTPUT

A class AB output stage with common-source transistors is used to achieve rail-to-rail output. For high-impedance loads (> 200Ω), the output voltage swing is typically 100mV from the supply rails. With 10Ω loads, a useful output swing can be achieved while maintaining high open-loop gain. See the typical characteristic curve *Output Voltage Swing vs Output Current*.



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Figure 1. Simplified Schematic



OUTPUT DRIVE

The OPA354's output stage can supply a continuous output current of ± 100 mA and still provide approximately 2.7V of output swing on a 5V supply, as shown in Figure 2. For maximum reliability, it is not recommended to run a continuous DC current in excess of ± 100 mA. Refer to the typical characteristic curve *Output Voltage Swing vs Output Current*. For supplying continuous output currents greater than ± 100 mA, the OPA354 may be operated in parallel, as shown in Figure 3.

The OPA354 will provide peak currents up to 200mA, which corresponds to the typical short-circuit current. Therefore, an on-chip thermal shutdown circuit is provided to protect the OPA354 from dangerously high junction temperatures. At 160°C, the protection circuit will shut down the amplifier. Normal operation will resume when the junction temperature cools to below 140°C.

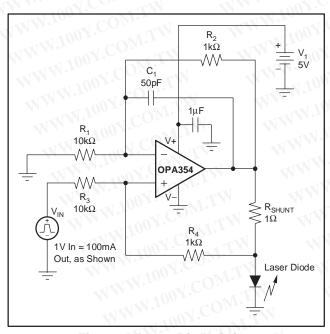


Figure 2. Laser Diode Driver

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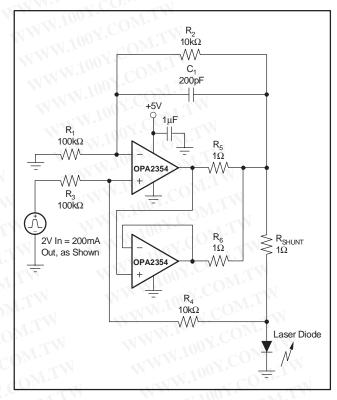


Figure 3. Parallel Operation

VIDEO

The OPA354 output stage is capable of driving standard back-terminated 75 Ω video cables, as shown in Figure 4. By back-terminating a transmission line, it does not exhibit a capacitive load to its driver. A properly back-terminated 75 Ω cable does not appear as capacitance; it presents only a 150 Ω resistive load to the OPA354 output.

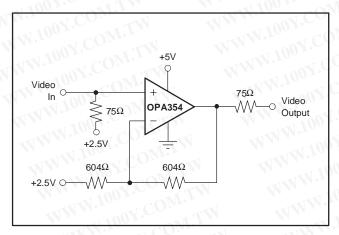


Figure 4. Single-Supply Video Line Driver



The OPA354 can be used as an amplifier for RGB graphic signals, which have a voltage of zero at the video black level, by offsetting and AC-coupling the signal. See Figure 5.

DRIVING ANALOG-TO-DIGITAL CONVERTERS

The OPA354 series op amps offer 60ns of settling time to 0.01%, making them a good choice for driving high- and medium-speed sampling A/D converters and reference

circuits. The OPA354 series provide an effective means of buffering the A/D converter's input capacitance and resulting charge injection while providing signal gain. For applications requiring high DC accuracy, the OPA350 series is recommended.

Figure 6 illustrates the OPA354 driving an A/D converter. With the OPA354 in an inverting configuration, a capacitor across the feedback resistor can be used to filter high-frequency noise in the signal.

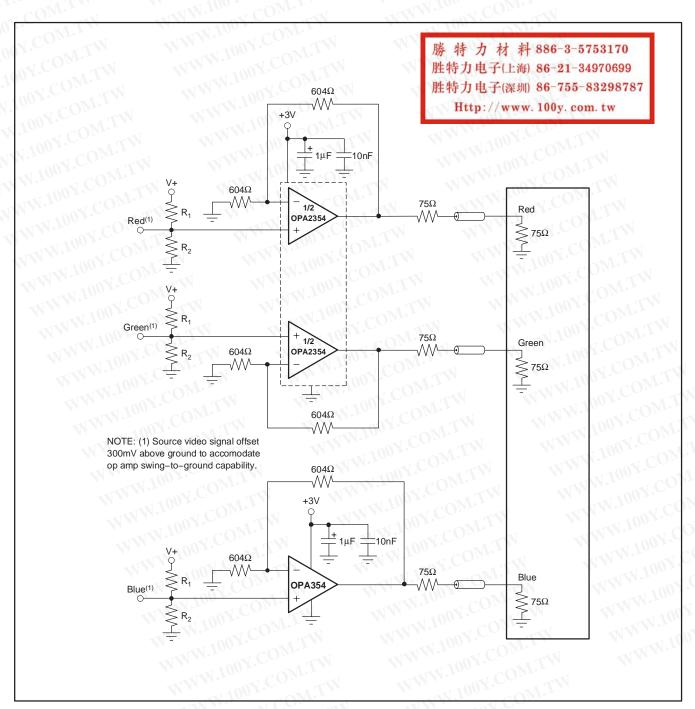


Figure 5. RGB Cable Driver



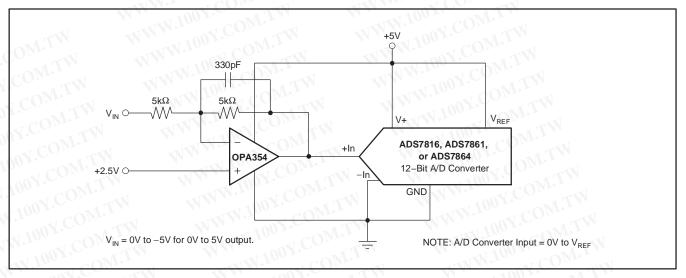


Figure 6. The OPA354 in Inverting Configuration Driving the ADS7816

CAPACITIVE LOAD AND STABILITY

The OPA354 series op amps can drive a wide range of capacitive loads. However, all op amps under certain conditions may become unstable. Op amp configuration, gain, and load value are just a few of the factors to consider when determining stability. An op amp in unity-gain configuration is most susceptible to the effects of capacitive loading. The capacitive load reacts with the op amp's output resistance, along with any additional load resistance, to create a pole in the small-signal response that degrades the phase margin. Refer to the typical characteristic curve *Frequency Response for Various CL* for details.

The OPA354's topology enhances its ability to drive capacitive loads. In unity gain, these op amps perform well with large capacitive loads. Refer to the typical characteristic curve *Recommended R_S* vs Capacitive Load and *Frequency Response* vs Capacitive Load for details.

One method of improving capacitive load drive in the unity-gain configuration is to insert a 10Ω to 20Ω resistor in series with the output, as shown in Figure 7. This significantly reduces ringing with large capacitive loads—see the typical characteristic curve Frequency Response vs Capacitive Load. However, if there is a resistive load in parallel with the capacitive load, $R_{\rm S}$ creates a voltage divider. This introduces a DC error at the output and slightly reduces output swing. This error may be insignificant. For instance, with $R_{\rm L}=10{\rm k}\Omega$ and $R_{\rm S}=20\Omega$, there is only about a 0.2% error at the output.

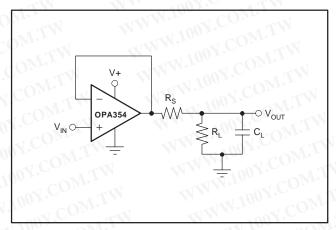


Figure 7. Series Resistor in Unity-Gain Configuration Improves Capacitive Load Drive

WIDEBAND TRANSIMPEDANCE AMPLIFIER

Wide bandwidth, low input bias current, and low input voltage and current noise make the OPA354 an ideal wideband photodiode transimpedance amplifier for low-voltage single-supply applications. Low-voltage noise is important because photodiode capacitance causes the effective noise gain of the circuit to increase at high frequency.



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The key elements to a transimpedance design, as shown in Figure 8, are the expected diode capacitance (including the parasitic input common-mode and differential-mode input capacitance (2 + 2)pF for the OPA354), the desired transimpedance gain (R_{F}), and the Gain-Bandwidth Product (GBW) for the OPA354 (100MHz). With these 3 variables set, the feedback capacitor value (C_{F}) may be set to control the frequency response.

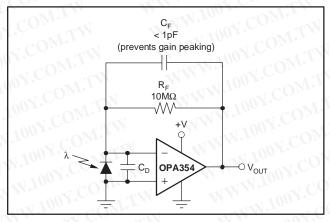


Figure 8. Transimpedance Amplifier

To achieve a maximally flat 2nd-order Butterworth frequency response, the feedback pole should be set to:

$$\frac{1}{2\pi R_F C_F} = \sqrt{\frac{GBP}{4\pi R_F C_D}} \tag{1}$$

Typical surface-mount resistors have a parasitic capacitance of around 0.2pF that must be deducted from the calculated feedback capacitance value.

Bandwidth is calculated by:

$$f_{-3dB} = \sqrt{\frac{GBP}{2\pi R_F C_D}} Hz$$
 (2)

For even higher transimpedance bandwidth, the high-speed CMOS OPA355 (200MHz GBW) or the OPA655 (400MHz GBW) may be used.

PCB LAYOUT

Good high-frequency printed circuit board (PCB) layout techniques should be employed for the OPA354. Generous use of ground planes, short and direct signal traces, and a suitable bypass capacitor located at the V+pin will assure clean, stable operation. Large areas of copper also provides a means of dissipating heat that is generated in normal operation.

Sockets are definitely not recommended for use with any high-speed amplifier.

A 10nF ceramic bypass capacitor is the minimum recommended value; adding a $1\mu F$ or larger tantalum capacitor in parallel can be beneficial when driving a low-resistance load. Providing adequate bypass capacitance is essential to achieving very low harmonic and intermodulation distortion.

POWER DISSIPATION

Power dissipation depends on power-supply voltage, signal and load conditions. With DC signals, power dissipation is equal to the product of output current times the voltage across the conducting output transistor, $V_S - V_O$. Power dissipation can be minimized by using the lowest possible power-supply voltage necessary to assure the required output voltage swing.

For resistive loads, the maximum power dissipation occurs at a DC output voltage of one-half the power-supply voltage. Dissipation with AC signals is lower. Application Bulletin AB-039 (SBOA022), *Power Amplifier Stress and Power Handling Limitations*, explains how to calculate or measure power dissipation with unusual signals and loads, and can be found at www.ti.com.

Any tendency to activate the thermal protection circuit indicates excessive power dissipation or an inadequate heatsink. For reliable operation, junction temperature should be limited to 150°C, maximum. To estimate the margin of safety in a complete design, increase the ambient temperature until the thermal protection is triggered at 160°C. The thermal protection should trigger more than 35°C above the maximum expected ambient condition of your application.

PowerPAD THERMALLY ENHANCED PACKAGE

Besides the regular SOT23-5 and MSOP-8, the single and dual versions of the OPA354 also come in SO-8 PowerPAD. The SO-8 PowerPAD is a standard-size SO-8 package where the exposed leadframe on the bottom of the package can be soldered directly to the PCB to create an extremely low thermal resistance. This will enhance the OPA354's power dissipation capability significantly and eliminates the use of bulky heatsinks and slugs traditionally used in thermal packages. This package can be easily mounted using standard PCB assembly techniques. NOTE: Since the SO-8 PowerPAD is pin-compatible with standard SO-8 packages, the OPA354 and OPA2354 can directly replace operational amplifiers in existing sockets. Soldering the PowerPAD to the PCB is always required, even with applications that have low power dissipation. This provides the necessary thermal and mechanical connection between leadframe die pad and the PCB.



The PowerPAD package is designed so that the leadframe die pad (or thermal pad) is exposed on the bottom of the IC, as shown in Figure 9. This provides an extremely low thermal resistance ($\theta_{\rm JC}$) path between the die and the exterior of the package. The thermal pad on the bottom of the IC can then be soldered directly to the PCB, using the PCB as a heatsink. In addition, plated-through holes (vias) provide a low thermal resistance heat flow path to the back side of the PCB.

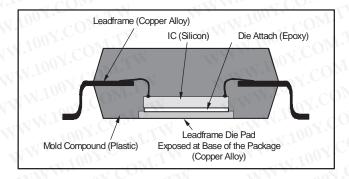


Figure 9. Section View of a PowerPAD Package

PowerPAD ASSEMBLY PROCESS

- 1. The PowerPAD must be connected to the device's most negative supply voltage, which will be ground in single-supply applications, and V- in split-supply applications.
- 2. Prepare the PCB with a top-side etch pattern, as shown in Figure 10. The exact land design may vary based on the specific assembly process requirements. There should be etch for the leads as well as etch for the thermal land.

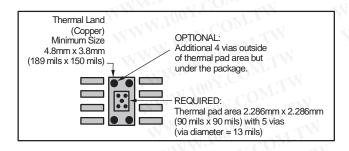


Figure 10. 8-Pin PowerPAD PCB Etch and Via Pattern

3. Place the recommended number of plated-through holes (or thermal vias) in the area of the thermal pad. These holes should be 13 mils in diameter. They are kept small so that solder wicking through the holes is not a problem during reflow. The minimum recommended number of holes for the SO-8 PowerPAD package is 5, as shown in Figure 10.

- 4. It is recommended, but not required, to place a small number of additional holes under the package and outside the thermal pad area. These holes provide additional heat paths between the copper thermal land and the ground plane. They may be larger because they are not in the area to be soldered, so wicking is not a problem. This is illustrated in Figure 10.
- 5. Connect all holes, including those within the thermal pad area and outside the pad area, to the internal ground plane or other internal copper plane for single-supply applications, and to V– for split-supply applications.
- 6. When laying out these holes, do not use the typical web or spoke via connection methodology, as shown in Figure 11. Web connections have a high thermal resistance connection that is useful for slowing the heat transfer during soldering operations. This makes soldering the vias that have ground plane connections easier. However, in this application, low thermal resistance is desired for the most efficient heat transfer. Therefore, the holes under the PowerPAD package should make their connection to the internal ground plane with a complete connection around the entire circumference of the plated-through hole.

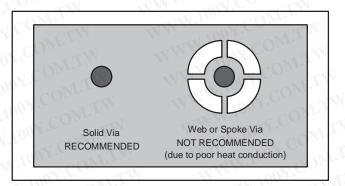


Figure 11. Via Connection

- 7. The top-side solder mask should leave the pad connections and the thermal pad area exposed. The thermal pad area should leave the 13 mil holes exposed. The larger holes outside the thermal pad area may be covered with solder mask.
- 8. Apply solder paste to the exposed thermal pad area and all of the package terminals.
- 9. With these preparatory steps in place, the PowerPAD IC is simply placed in position and run through the solder reflow operation as any standard surface-mount component. This results in a part that is properly installed.

For detailed information on the PowerPAD package including thermal modeling considerations and repair procedures, please see Technical Brief SLMA002, PowerPAD Thermally Enhanced Package, located at www.ti.com.

PACKAGE OPTION ADDENDUM



25-Feb-2005

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan ⁽²⁾	Lead/Ball Finish	MSL Peak Temp ⁽³⁾
OPA2354AIDDA	ACTIVE	SO Power PAD	DDA	8	100	None	CU SNPB	Level-3-235C-168 HR
OPA2354AIDDAR	ACTIVE	SO Power PAD	DDA	8	2500	None	CU SNPB	Level-3-235C-168 HR
OPA2354AIDGKR	ACTIVE	MSOP	DGK	8	2500	None	CU NIPDAU	Level-1-220C-UNLIM
OPA2354AIDGKT	ACTIVE	MSOP	DGK	8	250	None	CU NIPDAU	Level-1-220C-UNLIM
OPA354AIDBVR	ACTIVE	SOT-23	DBV	5	3000	None	CU NIPDAU	Level-3-250C-168 HR
OPA354AIDBVT	ACTIVE	SOT-23	DBV	5	250	None	CU NIPDAU	Level-3-250C-168 HR
OPA354AIDDA	ACTIVE	SO Power PAD	DDA	8	100	None	Call TI	Level-2-235C-1 YEAR
OPA354AIDDAR	ACTIVE	SO Power PAD	DDA	8	2500 N	None	Call TI	Level-1-235C-UNLIM
OPA4354AID	ACTIVE	SOIC	D CC	14	58	None	CU NIPDAU	Level-1-220C-UNLIM
OPA4354AIDR	ACTIVE	SOIC	100 D	14	2500	None	CU NIPDAU	Level-1-220C-UNLIM
OPA4354AIPWR	ACTIVE	TSSOP	PW	14	2500	None	CU NIPDAU	Level-3-220C-168 HR
OPA4354AIPWRG4	PREVIEW	TSSOP	PW	14	2500	None	Call TI	Call TI
OPA4354AIPWT	ACTIVE	TSSOP	PW	14	250	None	CU NIPDAU	Level-3-220C-168 HR

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - May not be currently available - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

None: Not yet available Lead (Pb-Free).

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Green (RoHS & no Sb/Br): TI defines "Green" to mean "Pb-Free" and in addition, uses package materials that do not contain halogens, including bromine (Br) or antimony (Sb) above 0.1% of total product weight.

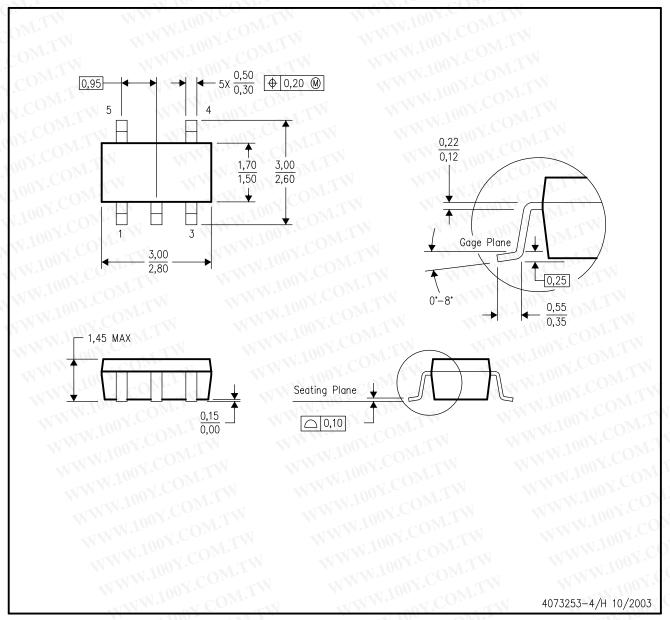
(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDECindustry standard classifications, and peak solder temperature.

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DBV (R-PDSO-G5)

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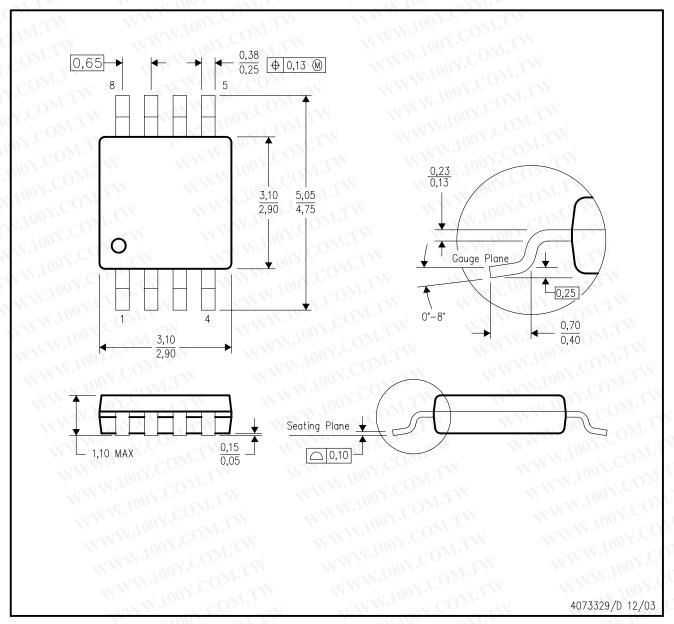
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- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion.
- D. Falls within JEDEC MO-178 Variation AA.



DGK (S-PDSO-G8)

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NOTES:

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- C. Body dimensions do not include mold flash or protrusion.
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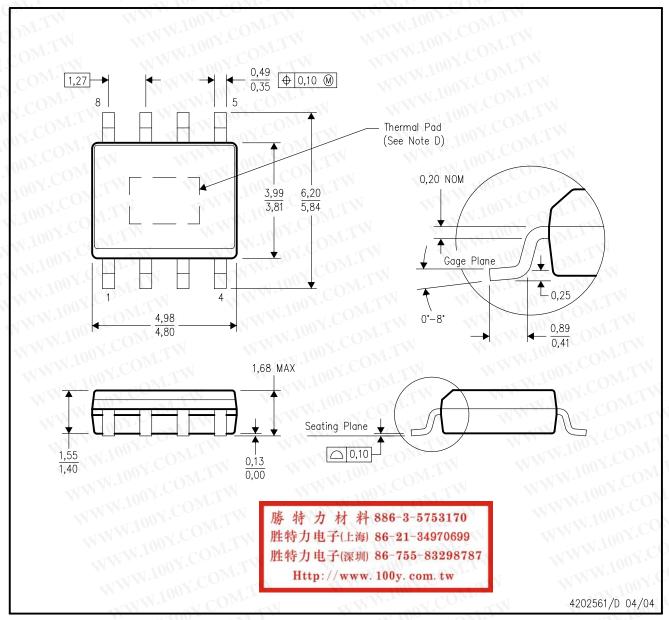
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DDA (R-PDSO-G8)

PowerPAD™ PLASTIC SMALL-OUTLINE PACKAGE



NOTES:

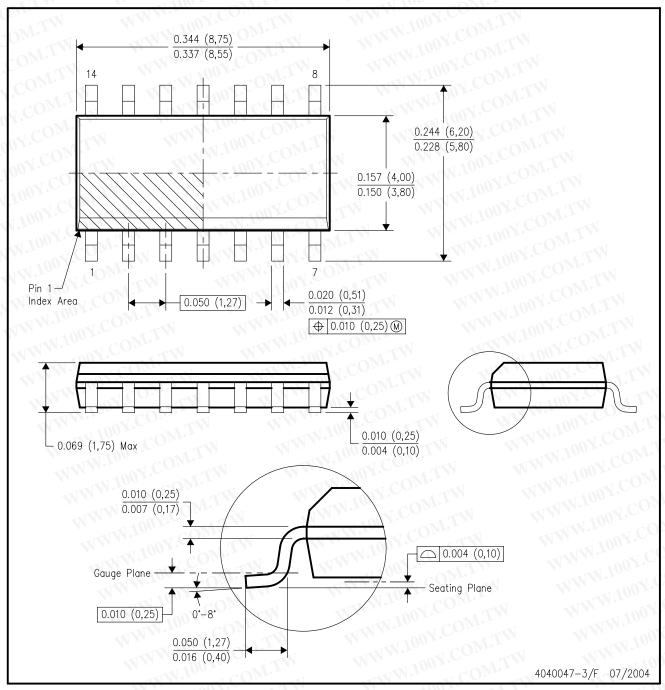
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- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion not to exceed 0,15.
- D. This package is designed to be soldered to a thermal pad on the board. Refer to Technical Brief, PowerPad Thermally Enhanced Package, Texas Instruments Literature No. SLMA002 for information regarding recommended board layout. This document is available at www.ti.com http://www.ti.com.

PowerPAD is a trademark of Texas Instruments.



D (R-PDSO-G14)

PLASTIC SMALL-OUTLINE PACKAGE



NOTES:

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- В. This drawing is subject to change without notice.
- Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15). C.
- Falls within JEDEC MS-012 variation AB.

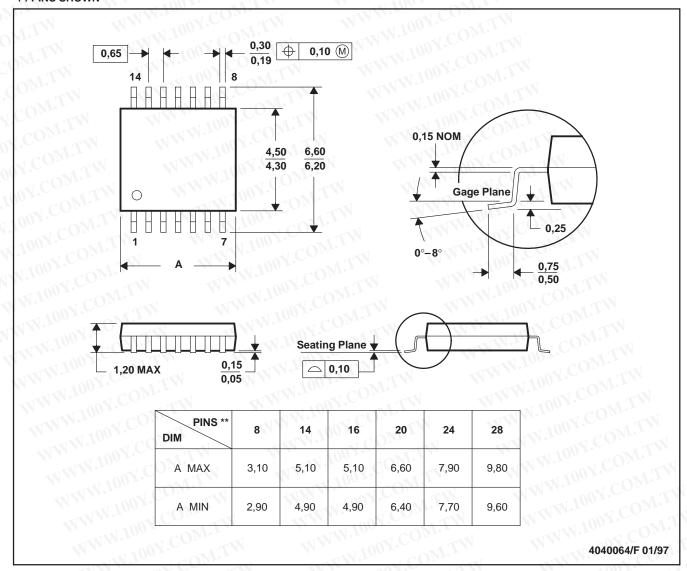


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PW (R-PDSO-G**)

14 PINS SHOWN

PLASTIC SMALL-OUTLINE PACKAGE



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D. Falls within JEDEC MO-153



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